# **SB20150FCT**

# SCHOTTKY BARRIER RECTIFIER

VOLTAGE: 150V CURRENT: 20.0A



### **FEATURE**

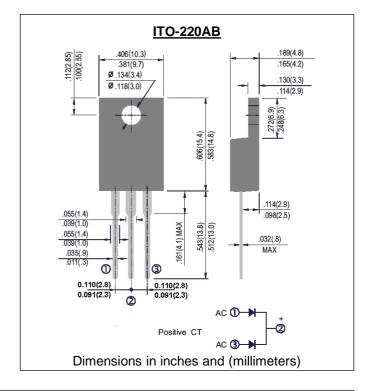
High current capability, Low forward voltage drop Low power loss, high efficiency High surge capability High temperature soldering guaranteed 250℃ /10sec/0.375" lead length at 5 lbs tension

### **MECHANICAL DATA**

Terminal: Plated axial leads solderable per MIL-STD 202E, method 208C

Case: Molded with UL-94 Class V-0 recognized Flame

Retardant Epoxy Polarity: Common Cathode Mounting position: any



### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half-wave, 60HZ, resistive or inductive load rating at 25℃, unless otherwise stated)

	SYMBOL	SB20150FCT	units
Maximum Recurrent Peak Reverse Voltage	Vrrm	150	V
Maximum RMS Voltage	Vrms	105	V
Maximum DC blocking Voltage	Vdc	150	V
Maximum Average Forward Rectified Current	If(av)	20	Α
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load	Ifsm	200	Α
Maximum Forward Voltage at 10A	Vf	0.90	V
Maximum DC Reverse Current Ta =25℃ at rated DC blocking voltage Ta =110℃	lr	50 1.0	μ A mA
Typical Thermal Resistance (Note 1)	Rth(jc)	4.2	€/W
Operating Junction and Storage Temperature Range	Tj, Tstg	-65 to +175	C

Note:

1.Thermal Resistance from Junction to Case

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#### RATINGS AND CHARACTERISTIC CURVES SB20150FCT

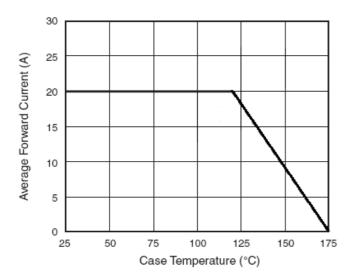


Figure 1. Forward Derating Curve (Total)

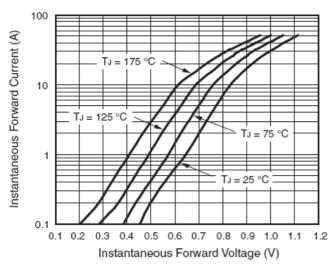


Figure 3. Typical Instantaneous Forward Characteristics
Per Diode

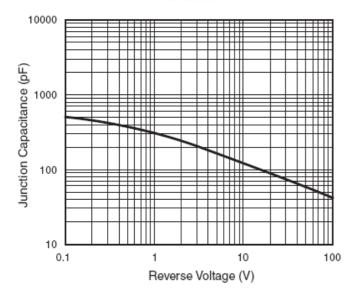


Figure 5. Typical Junction Capacitance Per Diode

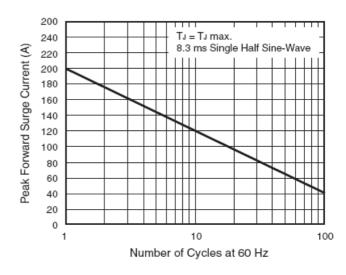


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

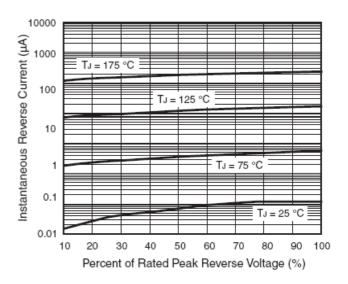


Figure 4. Typical Reverse Characteristics Per Diode

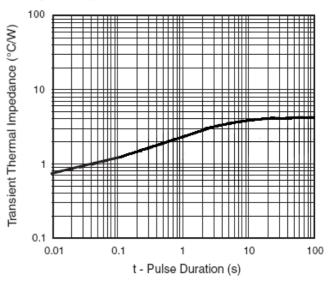


Figure 6. Typical Transient Thermal Impedance Per Diode

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